

2MBI650VXA-170E-50

IGBT Modules

IGBT MODULE (V series) 1700V / 650A / 2 in one package

Features

- High speed switching
- Voltage drive
- Low Inductance module structure

Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines

Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

| Items | Symbols | Conditions | Maximum ratings | Units |
|---|---------------------------------------|-----------------------|------------------|-------|
| Inverter | Collector-Emitter voltage | V _{CE} | 1700 | V |
| | Gate-Emitter voltage | V _{GE} | ±20 | V |
| | Collector current | I _C | Tc=25°C 900 | A |
| | | I _C pulse | Tc=100°C 650 | |
| | | -I _C | 1300 | |
| | | -I _C pulse | 650 | |
| | Collector power dissipation | P _C | 1 device 4150 | W |
| | | T _J | 175 | |
| Junction temperature | T _J | | 150 | °C |
| Operating junction temperature (under switching conditions) | T _{top} | | 150 | |
| Case temperature | T _C | | 150 | |
| Storage temperature | T _{stg} | | -40 ~ +150 | |
| Isolation voltage | between terminal and copper base (*1) | V _{iso} | AC : 1min. | VAC |
| | between thermistor and others (*2) | | | |
| Screw torque (*3) | Mounting | | M5 | N m |
| | Main Terminals | | M8 | |
| | Sense Terminals | | M4 | |
| | | | 2.1 | |

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable Value : Mounting 3.0 ~ 6.0 Nm (M5) Recommendable Value : Main Terminals 8.0 ~ 10.0 Nm (M8)
Recommendable Value : Sense Terminals 1.8 ~ 2.1 Nm (M4)

Electrical characteristics (at Tj= 25°C unless otherwise specified)

| Items | | Symbols | Conditions | | Characteristics | | | Units |
|--------------------------|--------------------------------------|---|---|-----------------------|-----------------|------|------|-------|
| | | | | | min. | typ. | max. | |
| Inverter | Zero gate voltage collector current | I _{CEs} | V _{GE} = 0V, V _{CE} = 1700V | | - | - | 4.0 | mA |
| | Gate-Emitter leakage current | I _{GES} | V _{CE} = 0V, V _{GE} = ±20V | | - | - | 800 | nA |
| | Gate-Emitter threshold voltage | V _{GE (th)} | V _{CE} = 20V, I _C = 650mA | | 6.0 | 6.5 | 7.0 | V |
| | Collector-Emitter saturation voltage | V _{CE (sat)} (terminal) (*4) | V _{GE} = 15V I _C = 650A | T _J =25°C | - | 2.10 | 2.55 | V |
| | | | | T _J =125°C | - | 2.50 | - | |
| | | | | T _J =150°C | - | 2.55 | - | |
| | | V _{CE (sat)} (chip) | | T _J =25°C | - | 2.00 | 2.45 | |
| | | | | T _J =125°C | - | 2.40 | - | |
| | Internal gate resistance | R _{g(int)} | - | | - | 1.75 | - | Ω |
| | Input capacitance | C _{ies} | V _{CE} = 10V, V _{GE} = 0V, f = 1MHz | | - | 63 | - | nF |
| | Turn-on time | t _{on} | V _{CC} = 900V | | - | 1.25 | - | μsec |
| | | t _r | I _C = 650A | | - | 0.50 | - | |
| | | t _{r (i)} | V _{GE} = ±15V | | - | 0.15 | - | |
| | Turn-off time | t _{off} | R _G = +1.8/-2.7Ω | | - | 1.55 | - | μsec |
| | | t _f | L _s =70nH | | - | 0.15 | - | |
| | Forward on voltage | V _F (terminal) (*4) | V _{GE} = 0V I _F = 650A | T _J =25°C | - | 1.95 | 2.40 | V |
| T _J =125°C | | | | - | 2.20 | - | | |
| T _J =150°C | | | | - | 2.15 | - | | |
| V _F (chip) | | T _J =25°C | | - | 1.85 | 2.30 | | |
| | | T _J =125°C | | - | 2.10 | - | | |
| Reverse recovery time | t _{rr} | I _F = 650A | | - | 0.24 | - | μsec | |
| Thermistor | Resistance | R | T=25°C | | - | 5000 | - | Ω |
| | B value | B | T=100°C | | 465 | 495 | 520 | K |
| | | | T=25/50°C | | 3305 | 3375 | 3450 | |

Note *4: Please refer to page 6, there is definition of on-state voltage at terminal.

Thermal resistance characteristics

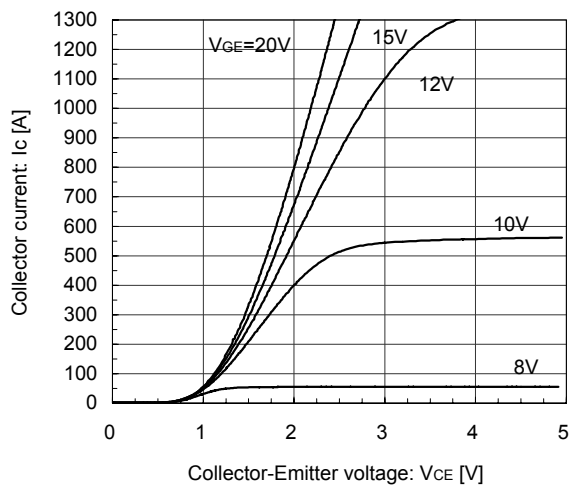
| Items | Symbols | Conditions | Characteristics | | | Units |
|---|----------------------|-----------------------|-----------------|--------|-------|-------|
| | | | min. | typ. | max. | |
| Thermal resistance (1device) | R _{th(j-c)} | Inverter IGBT | - | - | 0.036 | °C/W |
| | | Inverter FWD | - | - | 0.072 | |
| Contact thermal resistance (1device) (*5) | R _{th(c-f)} | with Thermal Compound | - | 0.0125 | - | |

Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

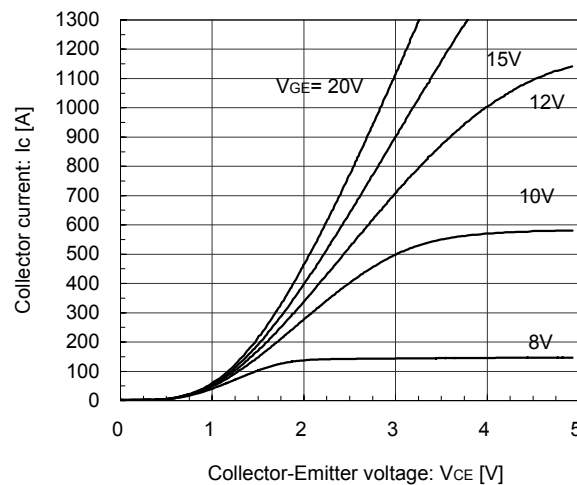
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.)
 $T_j = 25^\circ\text{C}$ / chip



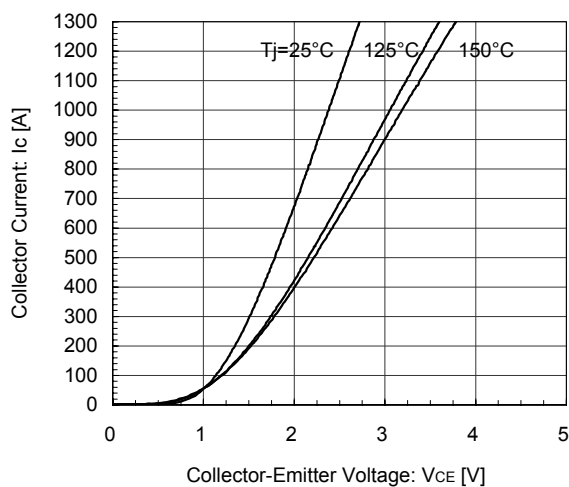
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.)
 $T_j = 150^\circ\text{C}$ / chip



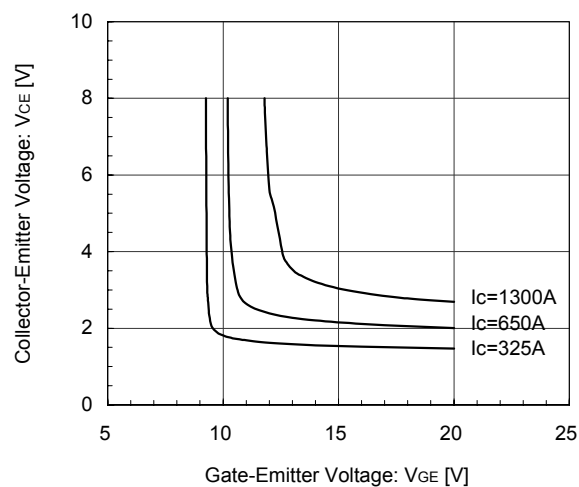
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.)
 $V_{GE} = 15\text{V}$ / chip



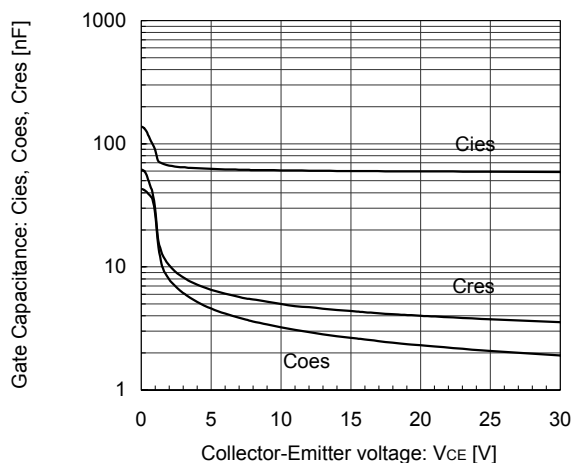
[INVERTER]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)
 $T_j = 25^\circ\text{C}$ / chip



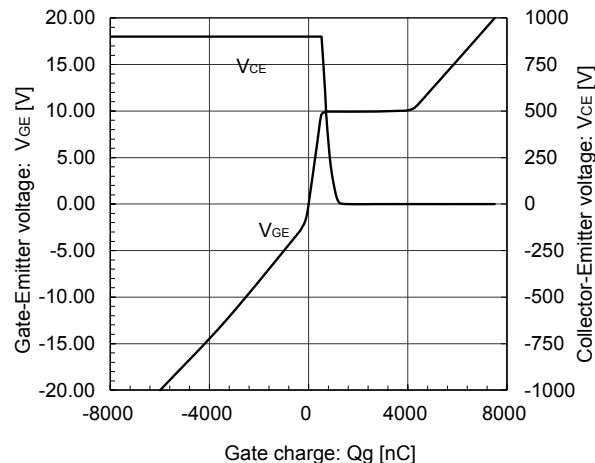
[INVERTER]

Gate Capacitance vs. Collector-Emitter Voltage (typ.)
 $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$, $T_j = 25^\circ\text{C}$



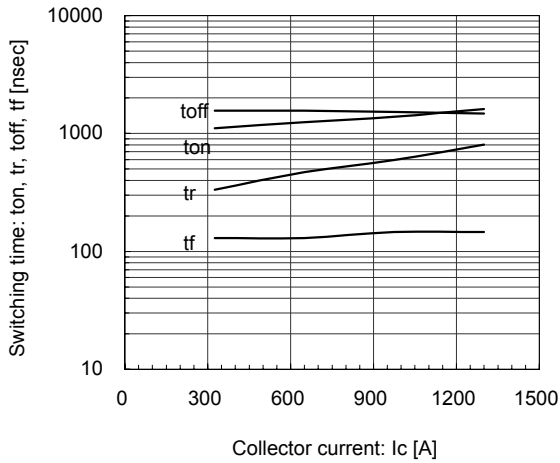
[INVERTER]

Dynamic Gate Charge (typ.)
 $V_{CC} = 900\text{V}$, $I_C = 650\text{A}$, $T_j = 25^\circ\text{C}$



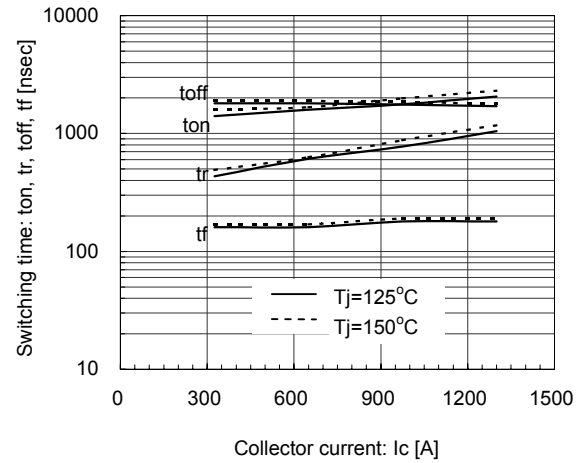
[INVERTER]

Switching time vs. Collector current (typ.)
 $V_{CC}=900V$, $V_{GE}=\pm 15V$, $R_G=+1.8/-2.7\Omega$, $T_J=25^\circ C$



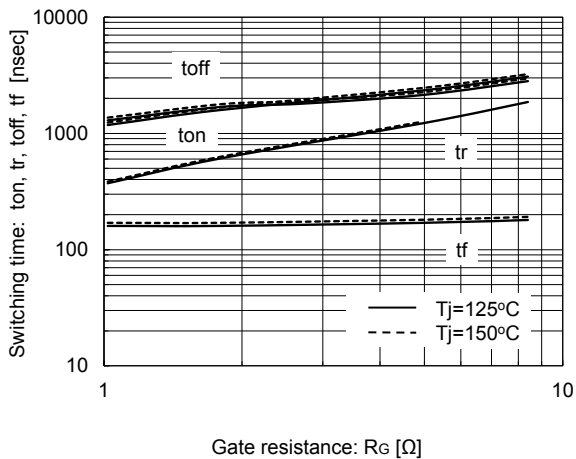
[INVERTER]

Switching time vs. Collector current (typ.)
 $V_{CC}=900V$, $V_{GE}=\pm 15V$, $R_G=+1.8/-2.7\Omega$, $T_J=125^\circ C, 150^\circ C$



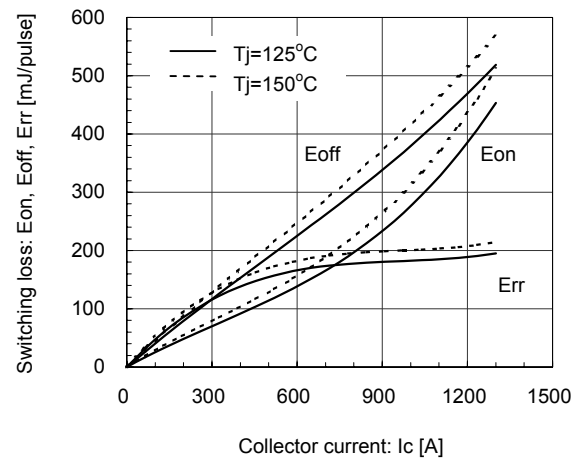
[INVERTER]

Switching time vs. Gate resistance (typ.)
 $V_{CC}=900V$, $I_C=650A$, $V_{GE}=\pm 15V$, $T_J=125^\circ C, 150^\circ C$



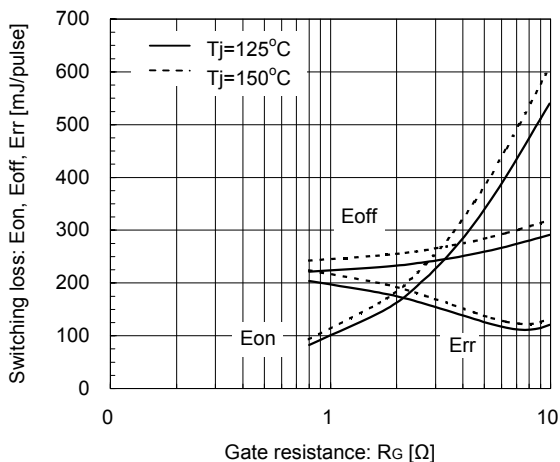
[INVERTER]

Switching loss vs. Collector current (typ.)
 $V_{CC}=900V$, $V_{GE}=\pm 15V$, $R_G=+1.8/-2.7\Omega$, $T_J=125^\circ C, 150^\circ C$



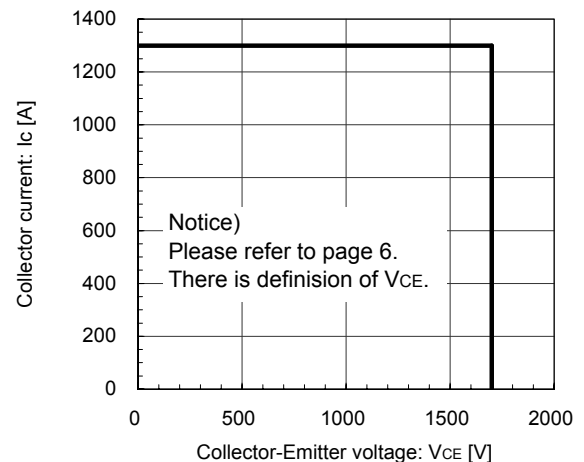
[INVERTER]

Switching loss vs. Gate resistance (typ.)
 $V_{CC}=900V$, $I_C=650A$, $V_{GE}=\pm 15V$, $T_J=125^\circ C, 150^\circ C$



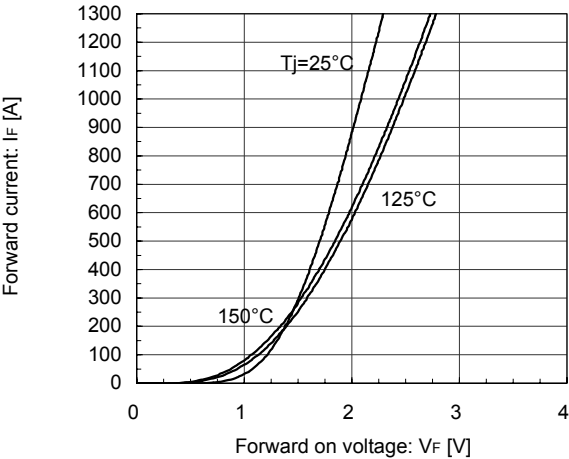
[INVERTER]

Reverse bias safe operating area (max.)
 $+V_{GE}=15V$, $-V_{GE}=15V$, $R_G=+1.8/-2.7\Omega$, $T_J=150^\circ C$



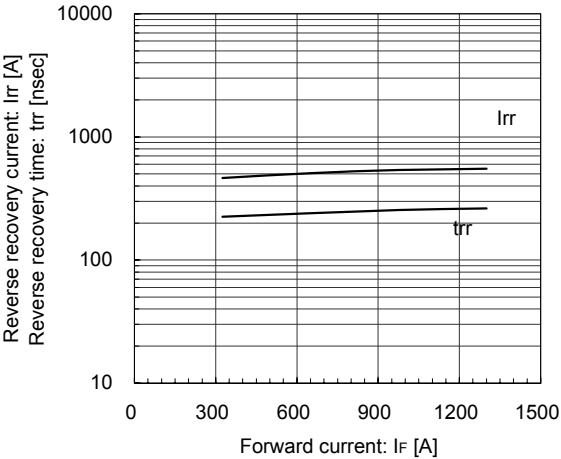
[INVERTER]

Forward Current vs. Forward Voltage (typ.)
chip



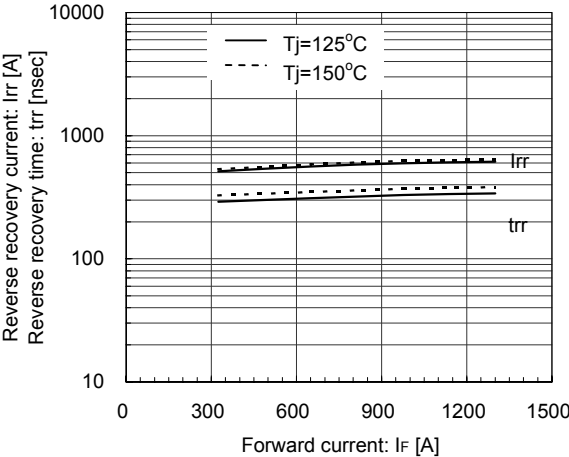
[INVERTER]

Reverse Recovery Characteristics (typ.)
VCC=900V, VGE=±15V, RG=+1.8/-2.7Ω, TJ=25°C

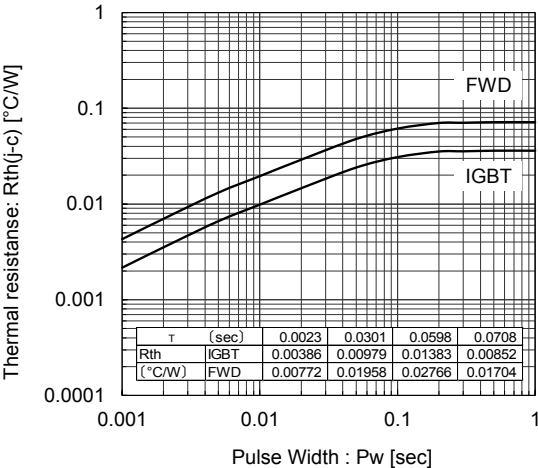


[INVERTER]

Reverse Recovery Characteristics (typ.)
VCC=900V, VGE=±15V, RG=+1.8/-2.7Ω, TJ=125°C, 150°C

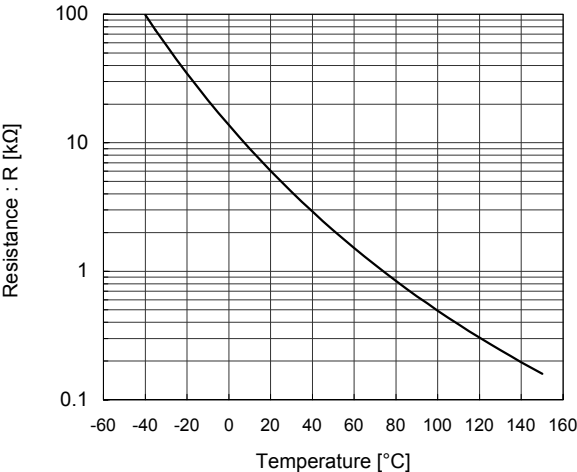


Transient Thermal Resistance (max.)



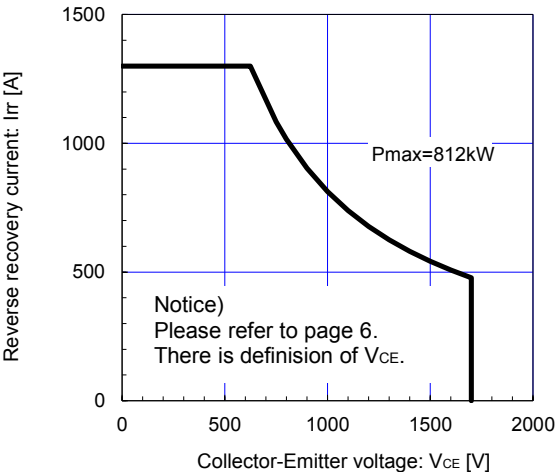
[THERMISTOR]

Temperature characteristic (typ.)

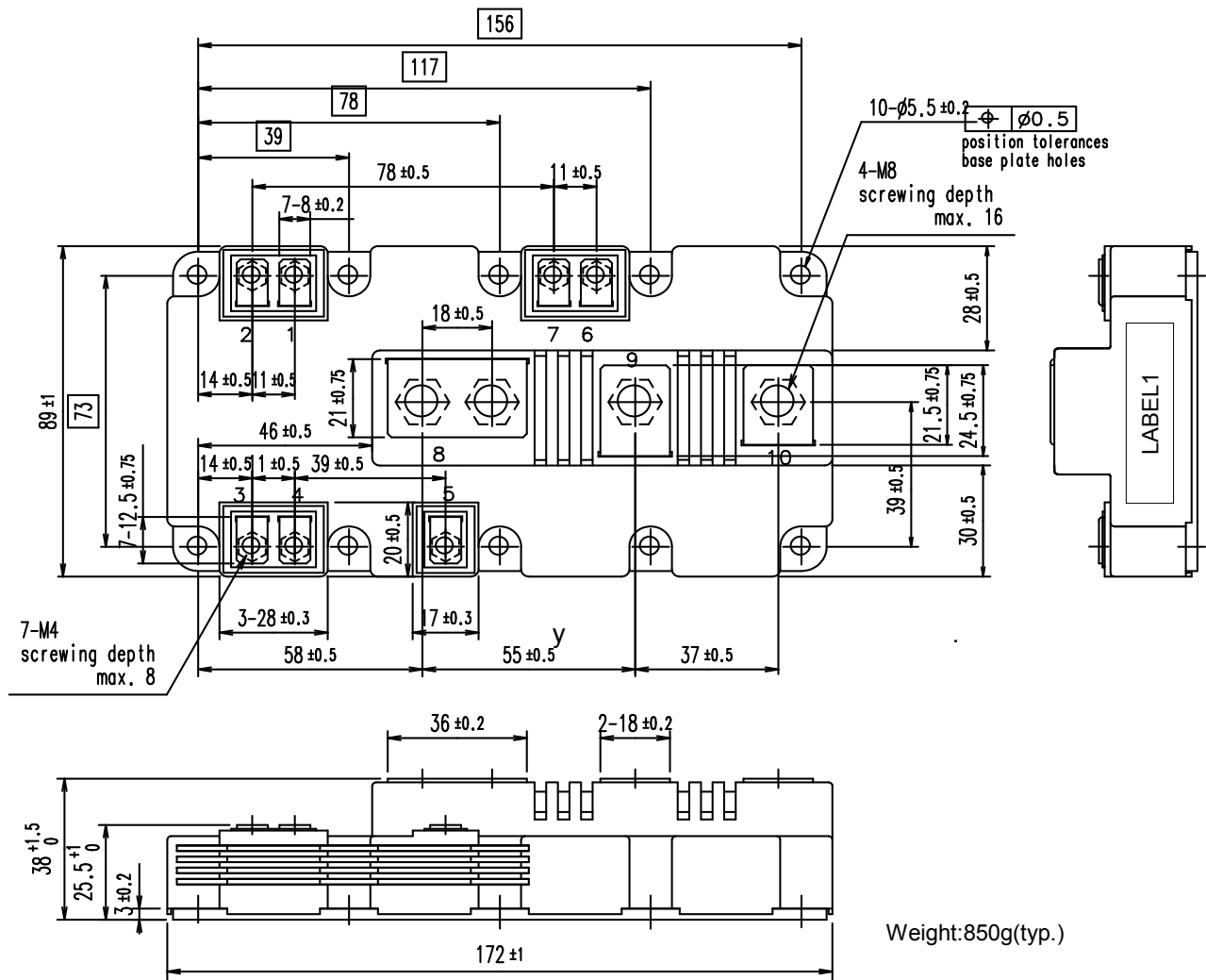


FWD safe operating area (max.)

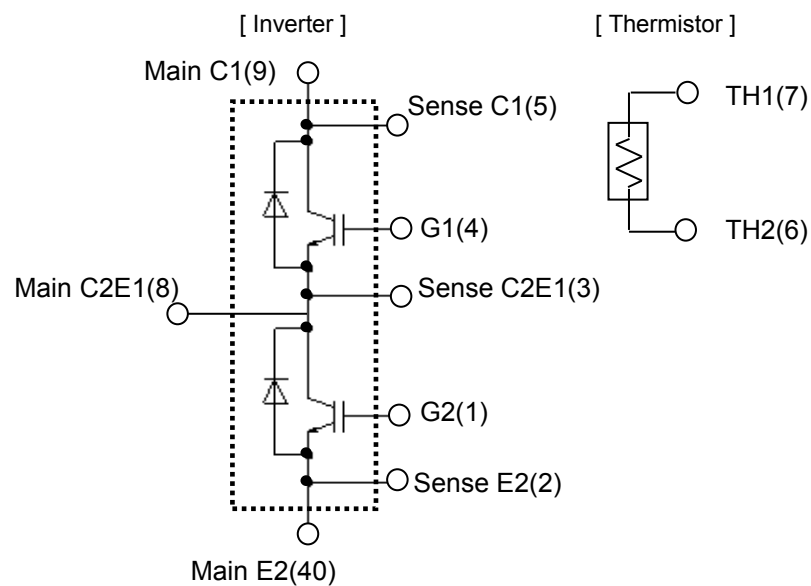
TJ=150°C



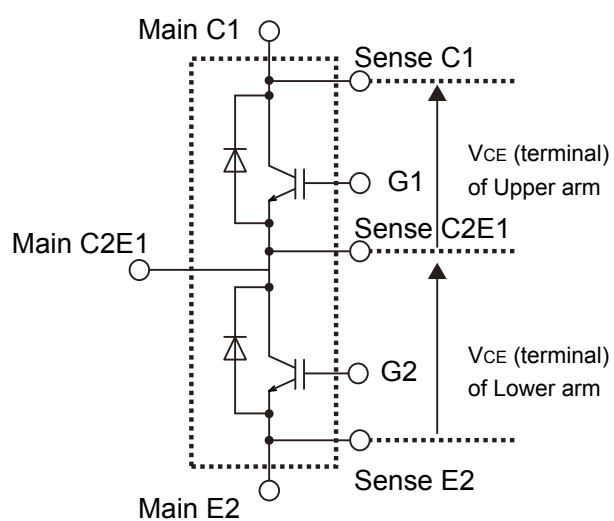
Outline Drawings (Unit: mm)



Equivalent Circuit



■ Definition of on-state voltage at terminal and switching characteristics



Fuji defined V_{CE} value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Switching characteristics of V_{CE} also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Please use these terminals whenever measure spike voltage and on-state voltage .

WARNING

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| | | | |
|-----------------|-------------------------|---|--------------------------|
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| • Machine tools | • Audiovisual equipment | • Electrical home appliances | • Personal equipment |
| | | | • Industrial robots etc. |
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| | |
|---|---|
| • Transportation equipment (mounted on cars and ships) | • Trunk communications equipment |
| • Traffic-signal control equipment | • Gas leakage detectors with an auto-shut-off feature |
| • Emergency equipment for responding to disasters and anti-burglary devices | • Safety devices |
| • Medical equipment | |
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| | | |
|--------------------------------|------------------------|-----------------------------|
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| • Submarine repeater equipment | | |
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